

8525

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852517					
SERIAL NUMBER	FILING DATE	CLASS	SUBCLASS	GROUP ART UNIT	EXAMINER
		257	49	2508-1104	SANDAT
		437	40		Froude

SHUNPEI HARAZAKI, TOKYO, JAPAN; HONRYONG AHANG, KANGOLONG, JAPAN; NAOTO KUSUMOTO, CANAGAWA, JAPAN; YASUHIKO TAKEHARA, KAGOSHIMA, JAPAN.

CONTINUING DATA***
VERIFIED

none

FOREIGN/PCT APPLICATIONS***
VERIFIED

JAPAN

3-88799

03/18/91

Foreign priority claimed	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no	AS FILED	STATE OR COUNTRY	SHEETS DRWGS.	TOTAL CLAIMS	INDEP. CLAIMS	FILING FEE RECEIVED	ATTORNEY'S DOCKET NO.
USC 119 conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no							
Unfiled and Acknowledged	Examiner's Initials		JPX	6	20	5	\$964.30	4756-711

SIABET, FRIEDMAN, LEEDON & PENGUSON
2010 CORPORATE RIDGE, STE. 600
MCLEAN, VA 22102

SEMICONDUCTOR MATERIAL AND METHOD FOR FORMING THE SAME AND THIN FILM
TRANSISTOR

U.S. DEPT. of COMM. Pat. & TM Office - PTO-436L (rev. 10-78)

PARTS OF APPLICATION FILED SEPARATELY					
NOTICE OF ALLOWANCE MAILED		PREPARED FOR ISSUE		CLAIMS ALLOWED	
		Assistant Examiner	Docket Clerk	Total Claims	Print Claim
ISSUE FEE		Primary Examiner		DRAWING	
Amount Due	Date Paid			Sheets Drwg.	Figs. Drwg.
Label Area		ISSUE CLASSIFICATION		ISSUE BATCH NUMBER	
		Class	Subclass		
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